

L Number	Hits	Search Text	DB	Time stamp
1	1	2000KR-0025706.ap,prai.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 12:11
8	1	1998KR-0042872.ap,prai.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 12:51
15	3270	(barrier cap capping liner lining protecting protector protection protective preventive preventing) near5 (insulating insulator insulation dielectric storage plate) near10 capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 13:11
22	1219	((barrier cap capping liner lining protecting protector protection protective preventive preventing) near5 (insulating insulator insulation dielectric storage plate) near10 capacitor) and (438/\$.ccls. 257/\$.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 13:07
36	4859	438/240,253,396.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 13:14
29	39	(barrier cap capping liner lining protecting protector protection protective preventive preventing) near5 (exposed near3 (insulating insulator insulation dielectric storage plate)) near10 capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 13:14
43	374	((barrier cap capping liner lining protecting protector protection protective preventive preventing) near5 (insulating insulator insulation dielectric storage plate) near10 capacitor) and 438/240,253,396.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 15:20
50	23	5,523,595	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 16:09
57	4	("5635420" "6261967" "6284654" "6316797").PN.	USPAT	2003/03/26 15:36
58	0	6528328.URPN.	USPAT	2003/03/26 15:37
59	4	("6146906" "6261967" "6284654" "6316797").PN.	USPAT	2003/03/26 15:37
60	8	("5489548" "5654224" "5807774" "5854104" "6200821" "6210979" "6211005" "6235542").PN.	USPAT	2003/03/26 15:51
61	1	6376325.URPN.	USPAT	2003/03/26 15:52
62	6	"6084765"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 16:29
69	118340	samsung.asn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 16:30
76	5614	ALD or ALE or (atomic adj layer adj (epitax\$3 deposit\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 16:31

83	118	samsung.asn. and (ALD or ALE or (atomic adj layer adj (epitax\$3 deposit\$3)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 16:32
90	79	(samsung.asn. and (ALD or ALE or (atomic adj layer adj (epitax\$3 deposit\$3)))) and (metal oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 16:33